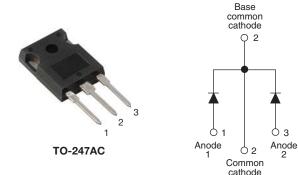


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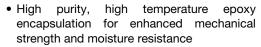
Schottky Rectifier, 2 x 40 A

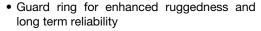


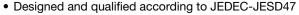
PRODUCT SUMMARY								
Package	TO-247AC							
I _{F(AV)}	2 x 40 A							
V _R	150 V							
V _F at I _F	0.71 V							
I _{RM} max.	26 mA at 125 °C							
T _J max.	175 °C							
Diode variation	Common cathode							
E _{AS}	0.5 mJ							

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- · High frequency operation







 Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>







DESCRIPTION

The VS-80CPQ150... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform	80	Α						
V _{RRM}		150	V						
I _{FSM}	t _p = 5 μs sine	1930	Α						
V _F	40 A _{pk} , T _J = 125 °C (per leg)	0.71	V						
TJ		- 55 to 175	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-80CPQ150PbF	VS-80CPQ150-N3	UNITS					
Maximum DC reverse voltage	V _R	150 150		V					
Maximum working peak reverse voltage	V_{RWM}	150	150	V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDI	VALUES	UNITS				
Maximum average per leg forward current See fig. 5 per device			50 % duty cycle at T _C = 150 °C, rectangular waveform -		40	^			
		I _{F(AV)}			80				
Maximum peak one cycle non-repetitive surge current per leg See fig. 7			5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	1930	A			
		I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	500				
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 1.0 A, L = 1 mH		0.5	mJ			
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximum	o in 1 µs um V _A = 1.5 x V _R typical	1.0	Α			



VS-80CPQ150PbF, VS-80CPQ150-N3

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS			
Maximum forward voltage drop per leg See fig. 1		40 A	T _{.1} = 25 °C	0.82	0.86				
	V _{FM} ⁽¹⁾	80 A	11 = 23 0	0.97	1.09	V			
	VFM (1)	40 A	T _{.1} = 125 °C	0.67	0.71				
		80 A	1j = 125 C	0.80	0.85				
Maximum reverse	I _{RM}	T _J = 25 °C	V _B = Rated V _B	10	200	μA			
leakage current per leg See fig. 2		T _J = 125 °C	V _R = nateu V _R	12	26	mA			
Typical junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal ran	-	1100	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 r	-	7.5	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	-	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	IBOL TEST CONDITIONS		UNITS			
Maximum junction and st temperature range	orage	T _J , T _{Stg}		- 55 to 175	°C			
Maximum thermal resistation junction to case per leg	ince,	Б	DC operation See fig. 4	0.6				
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	0.3	°C/W			
Typical thermal resistance case to heatsink	e,	R _{thCS}	Mounting surface, smooth and greased	0.24				
Approximate weight				6	g			
Approximate weight				0.21	OZ.			
Manustinas taunus	minimum			6 (5)	kgf · cm			
Mounting torque	maximum			12 (10)	(lbf \cdot in)			
Marking device			Case style TO-247AC (JEDEC)	80CP	Q150			



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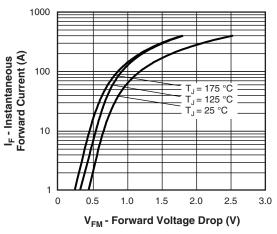


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

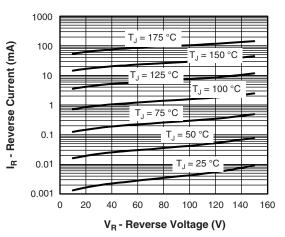


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

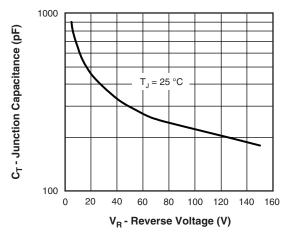


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

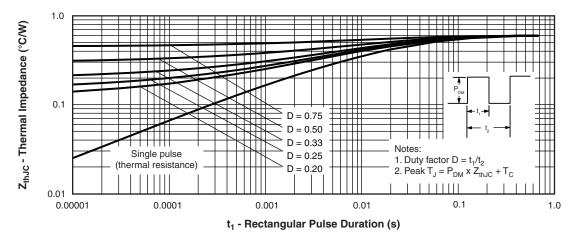


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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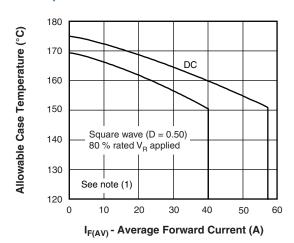
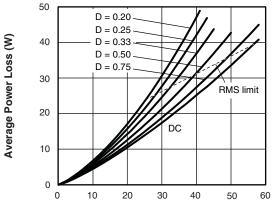


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)



I_{F(AV)} - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics (Per Leg)

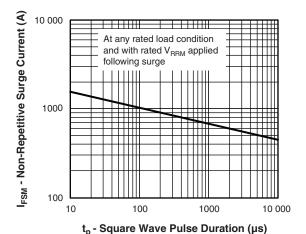


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

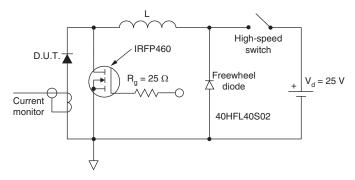


Fig. 8 - Unclamped Inductive Test Circuit

Note

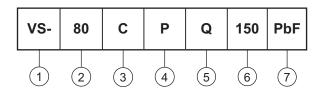
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

VS-80CPQ150PbF, VS-80CPQ150-N3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (80 = 80 A)

3 - Circuit configuration:

C = Common cathode

4 - Package:

P = TO-247

5 - Schottky "Q" series

6 - Voltage code (150 = 150 V)

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION									
VS-80CPQ150PbF	25	500	Antistatic plastic tube						
VS-80CPQ150-N3	25	500	Antistatic plastic tube						

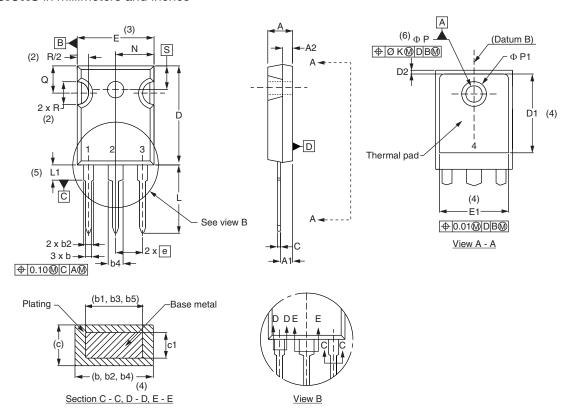
LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95542					
Dout moulting information	TO-247AC PbF	www.vishay.com/doc?95226					
Part marking information	TO-247AC -N3	www.vishay.com/doc?95007					



Vishay Semiconductors

TO-247 - 50 mils L/F

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		MILLIMETERS INCHE		NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	' 311	STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØΚ	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			Ν	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ØΡ	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	7.39	-	0.291	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	'BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- $^{(7)}$ Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



Legal Disclaimer Notice

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